

## IGBT MODULE (U series)

### 1200V / 25A / PIM



#### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C. Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit

#### ■ Applications

- Inverter for Motoe Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply

#### ■ Maximum ratings and characteristics

● Absolute maximum ratings ( $T_c=25^\circ\text{C}$  unless otherwise specified)

Item	Symbol	Condition	Rating	Unit
Inverter	Collector-Emitter voltage	$V_{CES}$	1200	V
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V
	Collector current	$I_c$	Continuous	25
			$T_c=25^\circ\text{C}$	
		$I_{CP}$	$T_c=80^\circ\text{C}$	15
			1ms	50
		$I_{CP}$	$T_c=25^\circ\text{C}$	30
			$T_c=80^\circ\text{C}$	
	- $I_c$			25
	- $I_c$ pulse	1ms		50
	Collector power dissipation	$P_c$	1 device	115
Brake	Collector-Emitter voltage	$V_{CES}$	1200	V
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V
	Collector current	$I_c$	Continuous	25
			$T_c=25^\circ\text{C}$	
		$I_{CP}$	$T_c=80^\circ\text{C}$	15
			1ms	50
		$I_{CP}$	$T_c=25^\circ\text{C}$	30
			$T_c=80^\circ\text{C}$	
	Collector power dissipation	$P_c$	1 device	115
	Repetitive peak reverse voltage	$V_{RRM}$		V
Converter	Repetitive peak reverse voltage	$V_{RRM}$	1200	V
	Average output current	$I_o$	50Hz/60Hz sine wave	25
	Surge current (Non-Repetitive)	$I_{FSM}$	$T_j=150^\circ\text{C}, 10\text{ms}$	260
	$I^2t$ (Non-Repetitive)	$I^2t$		338
	Operating junction temperature	$T_j$		$^\circ\text{C}$
	Storage temperature	$T_{stg}$		$^\circ\text{C}$
	Isolation voltage between terminal and copper base *2	$V_{iso}$	AC : 1 minute	AC 2500
	between thermistor and others *3			AC 2500
Mounting screw torque			3.5 *1	N·m

\*1 Recommendable value : 2.5 to 3.5 N·m (M5)

\*2 All terminals should be connected together when isolation test will be done.

\*3 Two thermistor terminals should be connected together, each other terminals should be connected together and shorted to base plate when isolation test will be done.

# IGBT Module

7MBR25UA120

## ● Electrical characteristics (T<sub>j</sub>=25°C unless otherwise specified)

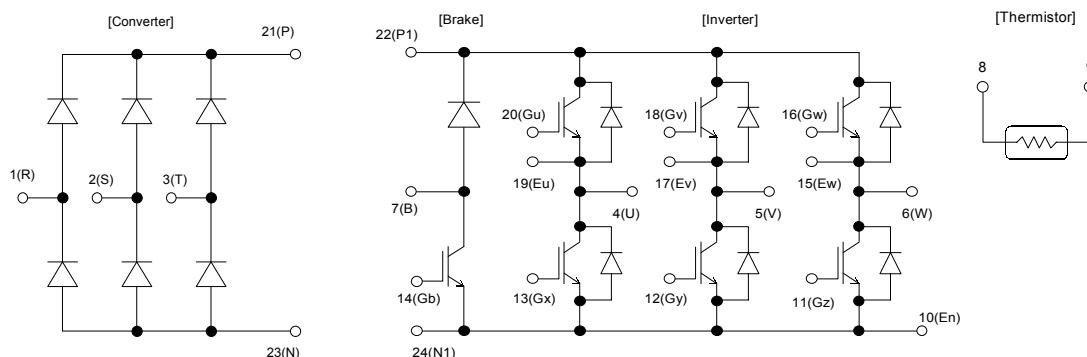
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Inverter	I <sub>CES</sub>	V <sub>CE</sub> =1200V, V <sub>GE</sub> =0V	-	-	1.0	mA
	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V	-	-	200	nA
	V <sub>GE(th)</sub>	V <sub>CE</sub> =20V, I <sub>c</sub> =25mA	4.5	6.5	8.5	V
	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> =15V I <sub>c</sub> =25A	T <sub>j</sub> =25°C	-	2.30	2.80
			T <sub>j</sub> =125°C	-	2.75	-
		V <sub>CE(sat)</sub> (chip)	T <sub>j</sub> =25°C	-	2.10	2.60
			T <sub>j</sub> =125°C	-	2.55	-
	C <sub>ies</sub>	V <sub>GE</sub> =0V, V <sub>CE</sub> =10V, f=1MHz	-	2	-	nF
	t <sub>on</sub>	V <sub>CC</sub> =600V I <sub>c</sub> =25A	-	0.41	1.20	μs
	t <sub>r</sub>		-	0.28	0.60	
	t <sub>r(i)</sub>		-	0.03	-	
	t <sub>off</sub>	V <sub>GE</sub> =±15V R <sub>G</sub> =68Ω	-	0.37	1.00	
	t <sub>f</sub>		-	0.07	0.30	
Brake	V <sub>F</sub> (terminal)	V <sub>GE</sub> =0V I <sub>f</sub> =25A	T <sub>j</sub> =25°C	-	2.95	3.55
			T <sub>j</sub> =125°C	-	2.55	-
		V <sub>F</sub> (chip)	T <sub>j</sub> =25°C	-	2.75	3.35
			T <sub>j</sub> =125°C	-	2.35	-
	t <sub>rr</sub>	I <sub>f</sub> =25A	-	-	0.35	μs
	I <sub>CES</sub>	V <sub>CE</sub> =1200V, V <sub>GE</sub> =0V	-	-	1.0	mA
	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V	-	-	200	nA
	V <sub>CE(sat)</sub> (terminal)	I <sub>c</sub> =25A V <sub>GE</sub> =15V	T <sub>j</sub> =25°C	-	2.30	2.80
			T <sub>j</sub> =125°C	-	2.75	-
		V <sub>CE(sat)</sub> (chip)	T <sub>j</sub> =25°C	-	2.10	2.60
			T <sub>j</sub> =125°C	-	2.55	-
Brake	t <sub>on</sub>	V <sub>CC</sub> =600V I <sub>c</sub> =25A	-	0.41	1.20	μs
	t <sub>r</sub>		-	0.28	0.60	
	t <sub>off</sub>	V <sub>GE</sub> =±15V R <sub>G</sub> =68Ω	-	0.37	1.00	
	t <sub>f</sub>		-	0.07	0.30	
Converter	I <sub>RRM</sub>	V <sub>R</sub> =1200V	-	-	1.0	mA
	V <sub>FM</sub>	I <sub>f</sub> =25 A V <sub>GE</sub> =0V	terminal	-	1.20	1.50
		chip	-	1.10	-	V
Thermistor	I <sub>RRM</sub>	V <sub>R</sub> =1600V	-	-	1.0	mA
	R	T=25°C	-	5000	-	Ω
		T=100°C	465	495	520	
B value	B	T=25/50°C	3305	3375	3450	K

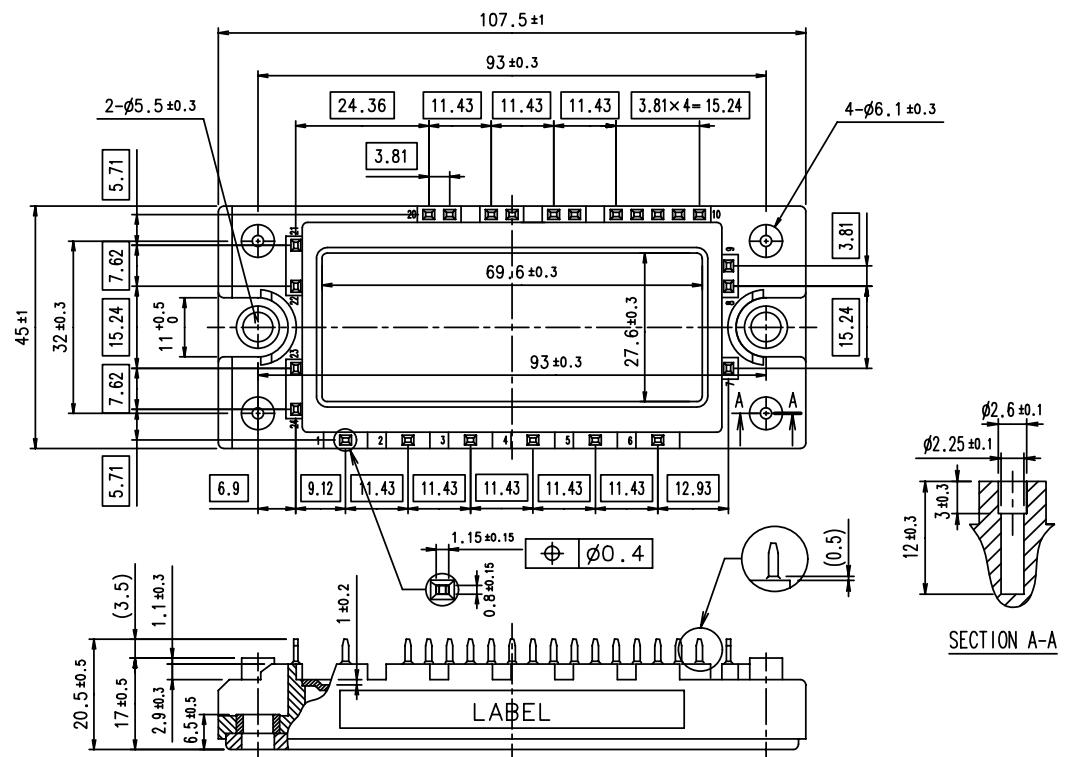
## ● Thermal resistance Characteristics

Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance ( 1 device )	R <sub>th(j-c)</sub>	Inverter IGBT	-	-	1.07	°C/W
		Inverter FWD	-	-	1.58	
		Brake IGBT	-	-	1.07	
		Converter Diode	-	-	0.90	
Contact thermal resistance *	R <sub>th(c-f)</sub>	With thermal compound	-	0.05	-	

\* This is the value which is defined mounting on the additional cooling fin with thermal compound

## ■ Equivalent Circuit Schematic



**■ Outline Drawings, mm**

□ shows theoretical dimension.  
( ) shows reference dimension.